2SK2736

Silicon N Channel DV-L MOS FET High Speed Power Switching

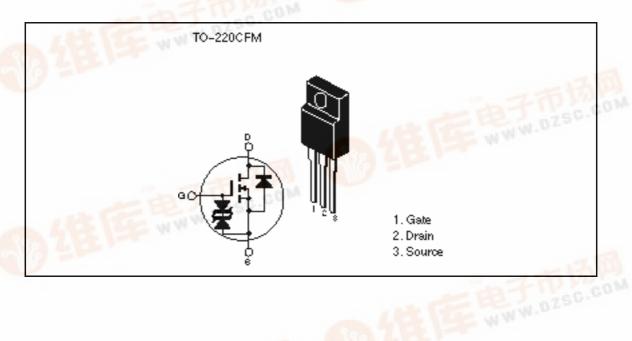
HITACHI

ADE-208-544 1st. Edition

Features

- Low on-resistance $R_{DS(on)} = 20 \text{ m}$ typ. $(V_{GS} = 10V, I_D = 15 \text{ A})$
- 4V gate drive devices.
- · High speed switching

Outline





2SK2736

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Ratings	Unit	
Drain to source voltage	$V_{\scriptscriptstyle DSS}$	30	V	
Gate to source voltage	$V_{\sf GSS}$	±20	V	
Drain current	I _D	30	Α	
Drain peak current	I _{D(pulse)} *1	120	Α	
Body to drain diode reverse drain current	I _{DR}	30	Α	
Channel dissipation	Pch*2	25	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW 10µs, duty cycle 1 %

2. Value at Tc = 25°C

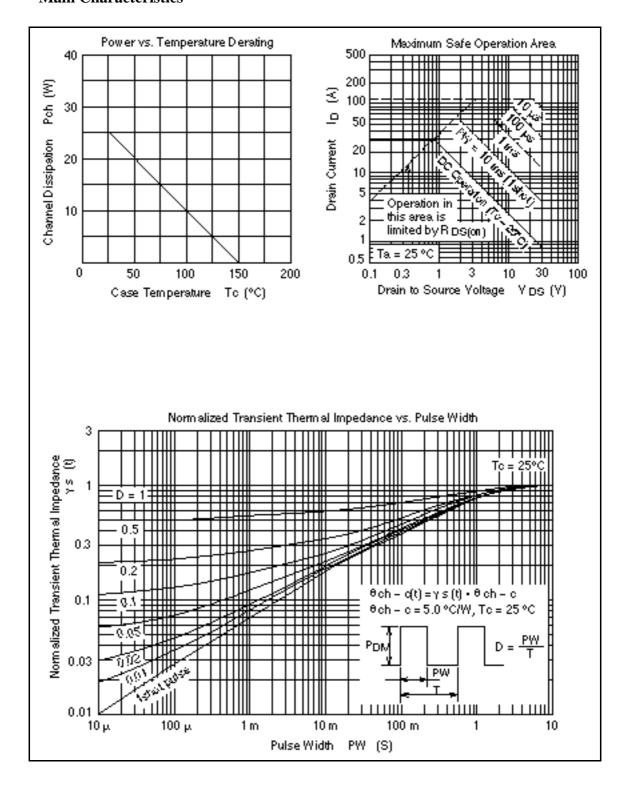
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10$ mA, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{G} = \pm 100 \mu A, V_{DS} = 0$
Zero gate voltege drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16V, V_{DS} = 0$
Gate to source cutoff voltage	$V_{\rm GS(off)}$	1.0	_	2.0	V	$I_D = 1 \text{mA}, V_{DS} = 10 \text{V}$
Static drain to source on state	R _{DS(on)}	_	20	28	m	$I_D = 15A, V_{GS} = 10V^{*1}$
resistance	R _{DS(on)}	_	35	50	m	$I_D = 15A, V_{GS} = 4V^{*1}$
Forward transfer admittance	y _{fs}	12	18	_	S	$I_D = 15A, V_{DS} = 10V^{*1}$
Input capacitance	Ciss	_	750	_	pF	V _{DS} = 10V
Output capacitance	Coss	_	520	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	210	_	pF	f = 1MHz
Turn-on delay time	$t_{d(on)}$	_	16	_	ns	$V_{GS} = 10V, I_{D} = 15A$
Rise time	t _r	_	260	_	ns	$R_{L} = 0.67$
Turn-off delay time	$t_{d(off)}$	_	85	_	ns	_
Fall time	t _f	_	90	_	ns	_
Body to drain diode forward voltage	V_{DF}	_	1.0	_	V	$I_F = 30A, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	45	_	ns	$I_F = 30A, V_{GS} = 0$ diF/ dt = 50A/µs

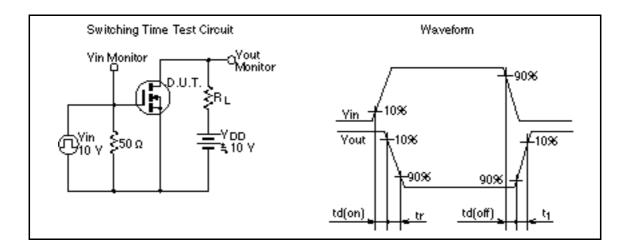
Note: 1. Pulse test

See characteristics curves of 2SK2684

Main Characteristics

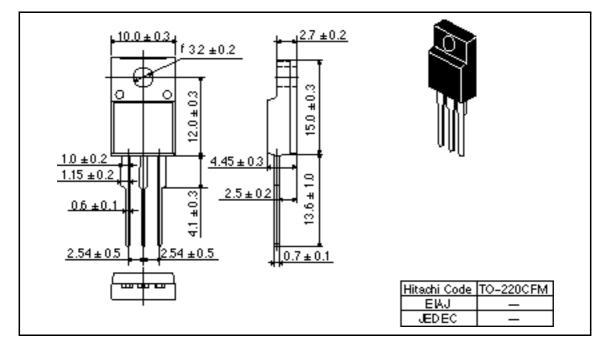


2SK2736



Package Dimensions

Unit: mm



When using this document, keep the following in mind:

- 1. This document may, wholly or partially, be subject to change without notice.
- 2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
- 3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
- 4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
- 5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
- 6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

HITACHI

Hitachi Itd

Semiconductor & IC DW. Nappon Bilda, 2:5-2, Ohtermachi, Chiyoda-ku, Tokyo 100, Japan Tet Tokyo (03, 3270-21111 Fax: 7:03, 3270-2109

For Jurther in forms I on write to:

Hitechi America, Ubd Semiconductor & IC Div. 2000 Sierre Foint Ferlaway Brisbana, CA. 94005-4835 USA Tat 445-589-8800 Feix 445-588-4207 Hitachi Burope GmbH
Bectronic Componente Group
Continental Burope
Domechar Strafe 3
D-85632 Feldkirchen
München
Tet (28349 94 80 0
Fex: 08949 29 30 00

Hitechi Burope Ltd.
Bedronic Components Div.
Northern Burope Headquerters
Whitebrook Ferk
Lower Cookhem Road
Naiderhead
Betishire SL68YA
United Kingdom
Tet 0628-885000
Fex 0628-778322

Hitechi Asia Pte. Ltd 45 Collyer Gusy \$20-00 Hitechi Tower Singapore 0104 Tet 535-2100 Fex: 535-1533

Hitechi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Centre, Herbor City, Centon Road Taim She Tau, Kowloon Hong Kong Tet 273592/8 Fex: 27306074

Copyright @Hitechi, Ltd., 1997. All rights reserved. Printed in Japan.